

NOT RECOMMENDED FOR NEW DESIGN **USE ZXTP2014G**

Ph Lead-free Green

DPLS4140E

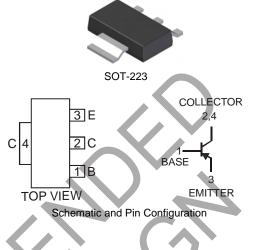
LOW V_{CE(SAT)} PNP SURFACE MOUNT TRANSISTOR

Features

- **Epitaxial Planar Die Construction**
- Ideally Suited for Automated Assembly Processes
- Ideal for Medium Power Switching or Amplification Applications
- Lead Free By Design/RoHS Compliant (Note 1)
- "Green" Device (Note 2)

Mechanical Data

- Case: SOT-223
- Case Material: Molded Plastic, "Green" Molding Compound. • UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C .
- Terminals: Finish Matte Tin annealed over Copper Leadframe (Lead Free Plating). Solderable per MIL-STD-202, Method 208
- Marking Information: See Page 4
- Ordering Information: See Page 4
- Weight: 0.115 grams (approximate)



Maximum Ratings @T_A = 25°C unless otherwise specified

Symbol	Value	Unit
V _{CBO}	-180	V
V _{CEO}	-140	V
V _{EBO}	-7	V
lc	-4	А
Ісм	-10	A
	V _{CBO} V _{CEO} V _{EBO} IC	V _{CBO} -180 V _{CEO} -140 V _{EBO} -7 I _C -4

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 3) @ T _A = 25°C	PD	1	W
Thermal Resistance, Junction to Ambient Air (Note 3) @ T _A = 25°C	R _{0JA}	125	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

No purposefully added lead. Notes: 1.

2.

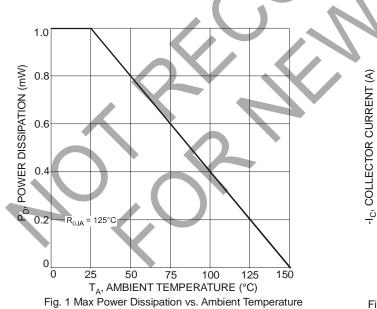
Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php. Device mounted on FR-4 PCB; pad layout as shown on page 4 or in Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf. 3.

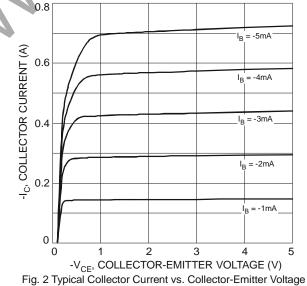


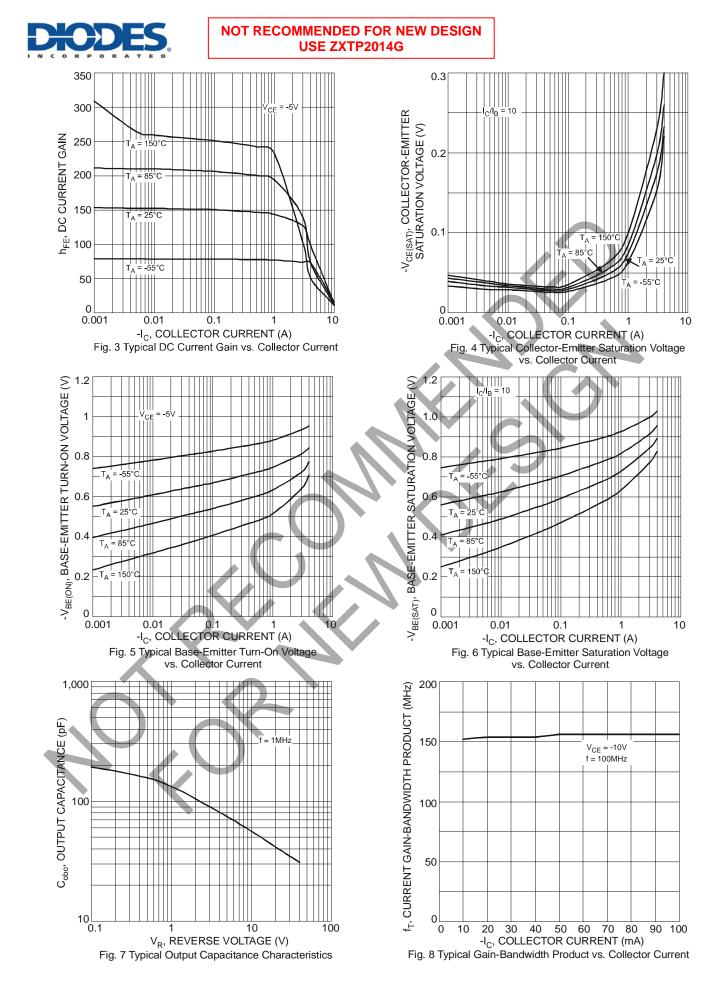
Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Turn	Max	Unit	Test Condition
	Symbol	IVIIN	Тур	wax	Unit	Test Condition
OFF CHARACTERISTICS (Note 4)		400	000	i	1/	
Collector-Base Breakdown Voltage	V _{(BR)CBO}	-180	-230		V	$I_{\rm C} = -100 \mu A, I_{\rm E} = 0$
Collector-Emitter Breakdown Voltage	V _{(BR)CEO}	-140	-190	—	V	$I_{\rm C} = -10 {\rm mA}, I_{\rm B} = 0$
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	-7	-8.5	—	V	$I_E = -100 \mu A, I_C = 0$
Collector Cutoff Current	Ісво	_	—	-20 -0.5	nA μA	$V_{CB} = -150V, I_E = 0$ $V_{CB} = -150V, I_E = 0,$ $T_A = 100^{\circ}C$
Emitter Cutoff Current	I _{EBO}	_	_	-10	nA	$V_{EB} = -6V, I_{C} = 0$
ON CHARACTERISTICS (Note 4)						
		_	-40	-60		I _C = -0.1A, I _B = -5mA
Collector-Emitter Saturation Voltage	14	_	-50	-80	mV	I _C = -0.5A, I _B = -50mA
Collector-Emitter Saturation voltage	V _{CE(SAT)}	_	-75	-120	IIIV	I _C = -1A, I _B = -100mA
		—	-175	-360	\sim	I _C = -3A, I _B = -300mA
Base-Emitter Saturation Voltage	V _{BE(SAT)}	_	-910	-1040	mV	I _C = -3A, I _B = -300mA
Base-Emitter Turn-On Voltage	V _{BE(ON)}	_	-810	-930	mV	$I_{C} = -3A, V_{CE} = -5V$
DC Current Gain	h _{FE}	100 100 45 —		300 	($I_{C} = -10$ mA, $V_{CE} = -5V$ $I_{C} = -1$ A, $V_{CE} = -5V$ $I_{C} = -3$ A, $V_{CE} = -5V$ $I_{C} = -10$ A, $V_{CE} = -5V$
SMALL SIGNAL CHARACTERISTICS						
Current Gain-Bandwidth Product	fт	\sim	150		MHz	I _C = -100mA, V _{CE} = -10V, f = 100MHz
Output Capacitance	C _{obo}	1	55		pF	$V_{CB} = -10V, f = 1MHz$
SWITCHING CHARACTERISTICS						-
Switching Times	ton t _{off}		85 430		ns	$I_{C} = -1A, I_{B1} = -100 \text{mA}$ $I_{B2} = 100 \text{mA}, V_{CC} = -50 \text{V}$

Notes: 4. Measured under pulsed conditions. Pulse width = 300μ s. Duty cycle $\leq 2\%$







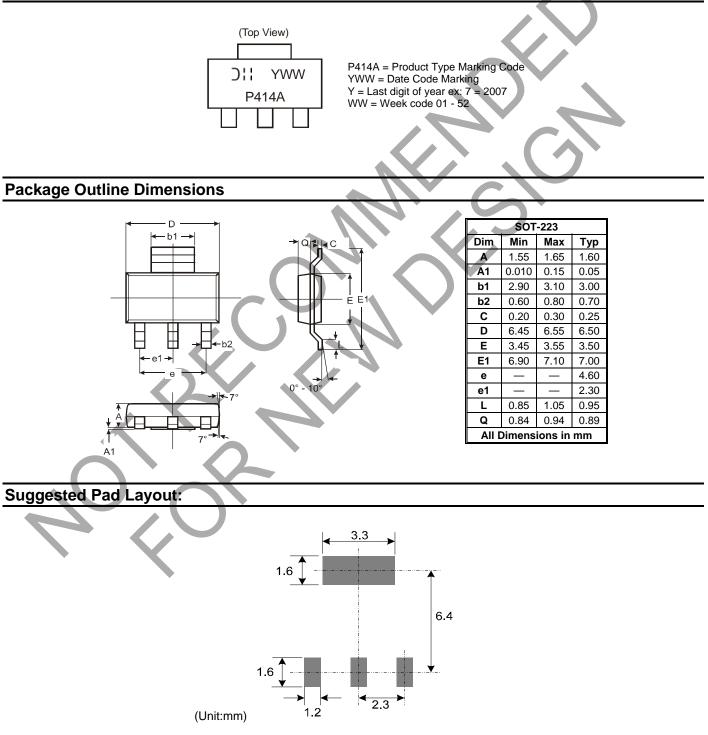


Ordering Information (Note 5)

Device	Packaging	Shipping
DPLS4140E -13	SOT-223	2500/Tape & Reel

Notes: 5. For packaging details, go to our website at http://www.diodes.com/ap02007.pdf.

Marking Information





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